

760-880MHz 16-20W RF PowerAmplifier

Features

 Frequency Range: 760-880MHz (min)

Gain: 39.5dB (typ.)
P_{3dB}: > +42.5dBm
P_{sat}: > +43dBm

 DCpower: 12V (nominal), 9-15V OK

SMA-Female connectorized

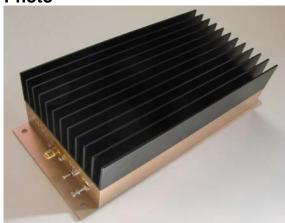
Typ. for Mobile Radio, HAM Radio, etc.

Description

HPA-820 is a 16Watt output (min. @P_{3dB}) RF PowerAmplifier; within frequencies of 760 to 880MHz; operating from a single 12VDC power supply (9-15VDC usable, but not recommended).

With proper (active) cooling is capable of **20Watt RFpower out** (@P_{sat}), under *special* (non-*standard*) warranty.

Photo



Electrical Specifications @ +25°C, Z_{in}=Z_{out}=50Ohm, V_{supply} = +12VDC IMPORTANT: MUST USE ACTIVE COOLING IF CASE TEMP. EXCEEDS 65°C or to ACHIEVE MAX. RFpower Output over 12W upto 20W (over +41dBm upto +43dBm), keeping under 18W recommended.

Parameter	Unit	Minimum	Typical	Maximum
Frequency Range	MHz	760		880
Small Signal Gain	dB	38.5	39.5	40.5
Output Power - 3dB gain compr. (P _{3dB})	dBm	+42.5	+43	
Output Power - saturated (P _{sat})	dBm	+43		
Reverse Isolation (S12)	dB		-65	-59
VSWR - Input (S11)	ratio:1	1.5 @880MHz	2.0 @820MHz	2.3 @760MHz
VSWR - Output (S22)	(unitless)	2.1 @830MHz	2.3	3.0
				@760MHz
VSWR - Load Tolerance (non-destructive)	ratio:1			6
Efficiency @838MHz & Pout in dBm	%	<26 @P _{out} <+40	33 @P _{out} +42	36 @P _{out} +43
DCpower Supply - voltage (unipolar, positive)	V	9 not	12	15 not
		recommended		recommended

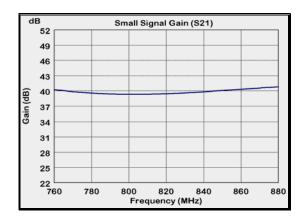


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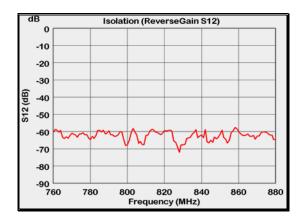
DCpower Supply - current: quiesc. (no RF)	А	1.3	1.5	
$@P_{out} = +40dBm$	Α		3.2	3.4
Size (incl. all hardware & heatsink [standard])	Inch	7.00 (L) x 3.25 (W) x 2.00 (H)		
Weight (incl. all hardware & heatsink [standard])	Oz	24		

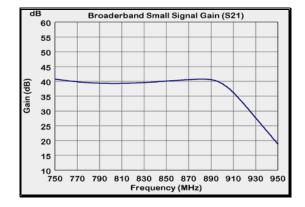
Typical Performance @ +25°C

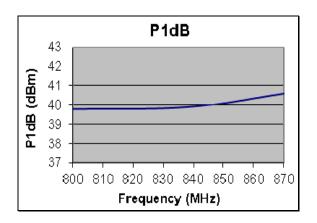
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(Power & S-parameters also available for

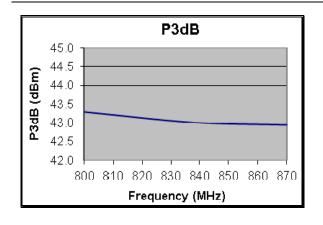


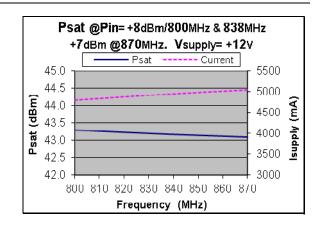






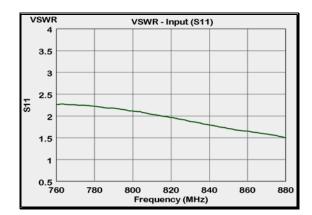
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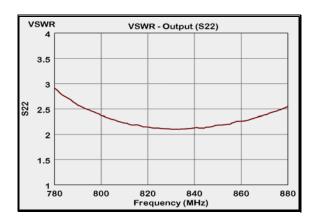




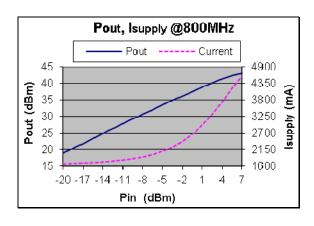
Typical Performance @ +25°C

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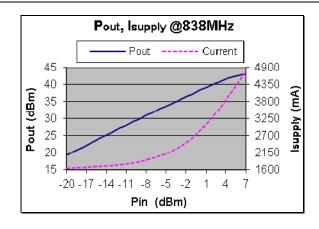


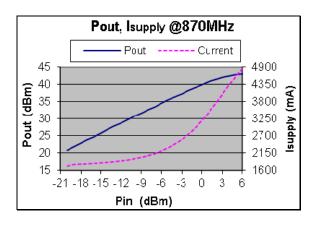
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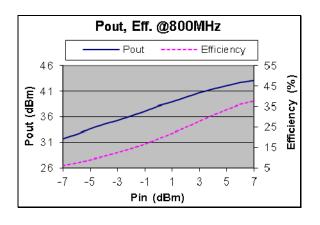




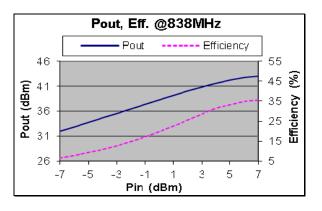
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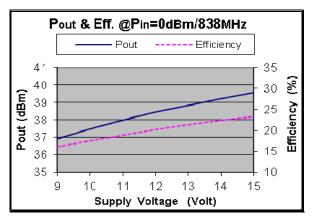


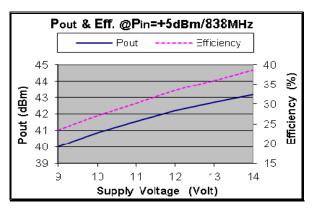




Typical Performance @ +25°C

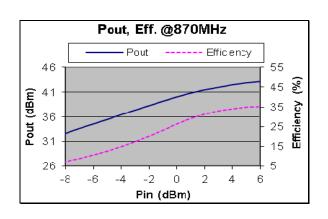


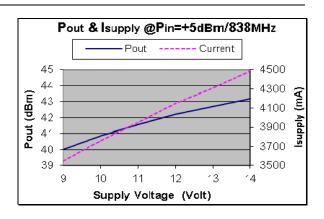


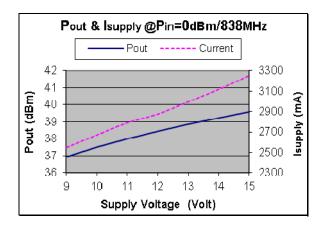




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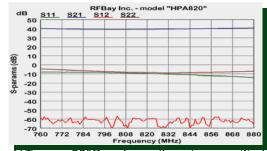




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Absolute Maximum Ratings

Parameter	Absolute Maximum
RF Input Power	+15dBm
Supply Voltage	+16V
Operating Temperature	-30 °C to +65 °C
Storage Temperature	-55 °C to +100 °C



The above parameters are independently guaranteed and are @Tcase <23°C, unless otherwise specified

APPLICATION NOTES (reliability):

• Thermal:

Specifications shown above as graphs, are at room temperature (23-25°C i.e. in a controlled environment), per international standard. If Amplifier's temperature is let rise significantly (e.g. towards max. 65-70°C) in customer's use, DCpower (supply) current may rise and stabilize at approx. 200-450mA higher values vs. shown in graphs, especially if at the same time RF PowerOut is driven beyond approx. 9Watt (contributing to selfheating, besides ambient temperature) - which is normal. Such increase in DCsupply current due to higher than standard ambient temperature, is less pronounced at low RF PowerOut: at below 1Watt it may add less than 90mA vs. current @25°C. Amplifier is designed to operate normal at ANY temperature or RF PowerOut within specs, this notice is only a recommendation to expect higher DCcurrent if user allows heat build-up far above standard 25°C. Stock Heatsink is removable & upgradeable by the user, additionally Mountplate (opposite of heatsink) is strongly recommended to mount on a surface conducting heat away (e.g. mass of metal); some customers use active cooling such as fans (for extreme environment, even liquid cooling is an option), however be careful to not generate ElectroStatic Fields harmful for RF/Microwave devices. Use of inadequate Heatsink or HeatSpreader instead of stock, or inappropriate thermal-interface-material (TIM, i.e. grease, paste, semi-solids) voids warranty; RF Bay Inc. reserves the right to determine if a unit submitted for warranty service had been thermally abused. The key to reliability, is not only to minimize temperature rise, but also avoid repetitive thermal gradient (shock) due to cold-hot-cold cycling; these Amplifiers are meant for Commercial (rather than Mission-Critical) Mobile communications; in particular in Base & Fixed station applications with long-term continuous transmission and a higher On-Off frequency, please consider derating, redundancy system, maintenance schedule, or otherwise assure reliability.

Oscillation & Load VSWR:

This amplifier's rugged design can withstand Load VSWR mismatch upto 6:1 (no degradation/destruction), guaranteed stable (no parasitic self-oscillation) for Pout<20Watt & Load VSWR under 3:1. If oscillation is observed, check if Load & Source impedances $Z_L = Z_S = 50$ Ohm; adding DCpower decoupling ceramic + electrolytic capacitors (in parallel, closest possible to amplifier & minimal parasitic inductance to Ground) may help but not necessary, because already present internally.

• ESD:

Sensitive to ESD voltages to approx. 1KiloVolt - as typical for RF/Microwave amplifiers, appropriate ESD precaution is required.



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• Mounting & DCpower connection:

Avoid excessive or torque (twisting) force onto DC terminals

Outline (compact version)

Also available as a standalone higher-resolution 3Dmodel (MCADsolid) & 2Ddrawing - see "Notes" on compact drawing (below):

